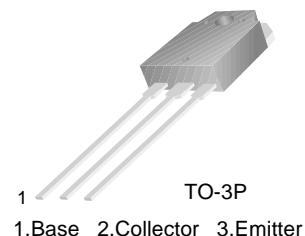


High Voltage Switch Mode Applications

- High Speed Switching
- Suitable for Switching Regulator and Motor Control



NPN Silicon Transistor

Absolute Maximum Ratings $T_C=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Value	Units
V_{CBO}	Collector-Base Voltage	700	V
V_{CEO}	Collector-Emitter Voltage	400	V
V_{EBO}	Emitter-Base Voltage	9	V
I_C	Collector Current (DC)	12	A
I_{CP}	Collector Current (Pulse)	24	A
I_B	Base Current	6	A
P_C	Collector Dissipation ($T_C=25^\circ\text{C}$)	130	W
T_J	Junction Temperature	150	$^\circ\text{C}$
T_{STG}	Storage Temperature	- 65 ~ 150	$^\circ\text{C}$

Electrical Characteristics $T_C=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
$V_{CEO(\text{sus})}$	Collector-Emitter Sustaining Voltage	$I_C = 10\text{mA}$, $I_B = 0$	400			V
I_{EBO}	Emitter Cut-off Current	$V_{EB} = 7\text{V}$, $I_C = 0$			1	mA
h_{FE}	DC Current Gain	$V_{CE} = 5\text{V}$, $I_C = 5\text{A}$ $V_{CE} = 5\text{V}$, $I_C = 8\text{A}$	8		40	
$V_{CE(\text{sat})}$	Collector-Emitter Saturation Voltage	$I_C = 5\text{A}$, $I_B = 1\text{A}$ $I_C = 8\text{A}$, $I_B = 1.6\text{A}$ $I_C = 12\text{A}$, $I_B = 3\text{A}$			1 1.5 3	V
$V_{BE(\text{sat})}$	Base-Emitter Saturation Voltage	$I_C = 5\text{A}$, $I_B = 1\text{A}$ $I_C = 8\text{A}$, $I_B = 1.6\text{A}$			1.2 1.6	V
C_{ob}	Output Capacitance	$V_{CB} = 10\text{V}$, $f = 0.1\text{MHz}$		180		pF
f_T	Current Gain Bandwidth Product	$V_{CE} = 10\text{V}$, $I_C = 0.5\text{A}$	4			MHz
t_{ON}	Turn ON Time	$V_{CC} = 125\text{V}$, $I_C = 8\text{A}$ $I_{B1} = -I_{B2} = 1.6\text{A}$ $R_L = 15.6\Omega$			1.1	μs
t_{STG}	Storage Time				3	μs
t_F	Fall Time				0.7	μs

* Pulse test: $PW \leq 300\mu\text{s}$, Duty cycle $\leq 2\%$ Pulse

Typical Characteristics

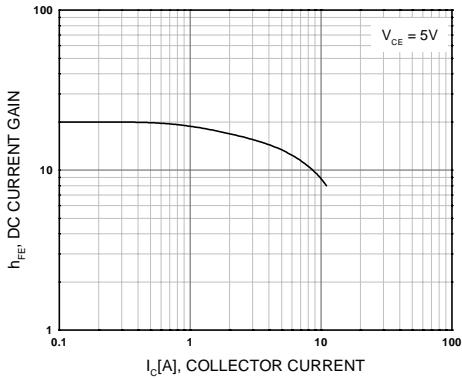


Figure 1. DC current Gain

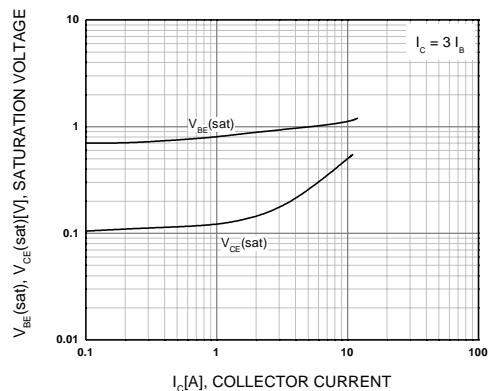


Figure 2. Base-Emitter Saturation Voltage
Collector-Emitter Saturation Voltage

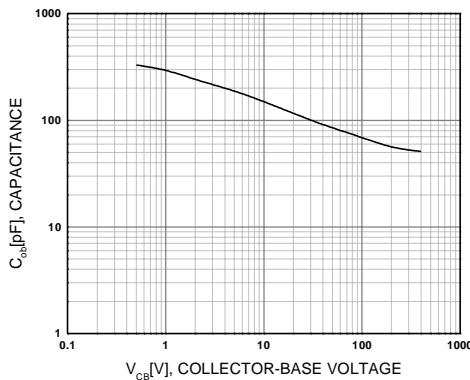


Figure 3. Collector Output Capacitance

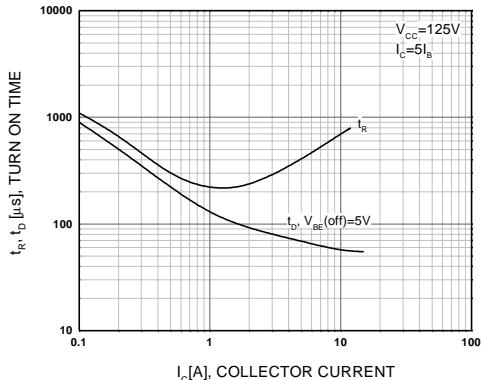


Figure 4. Turn On Time

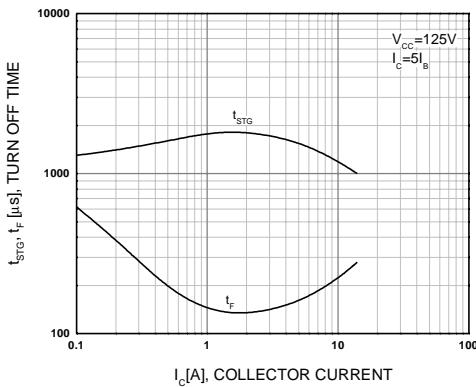
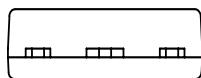
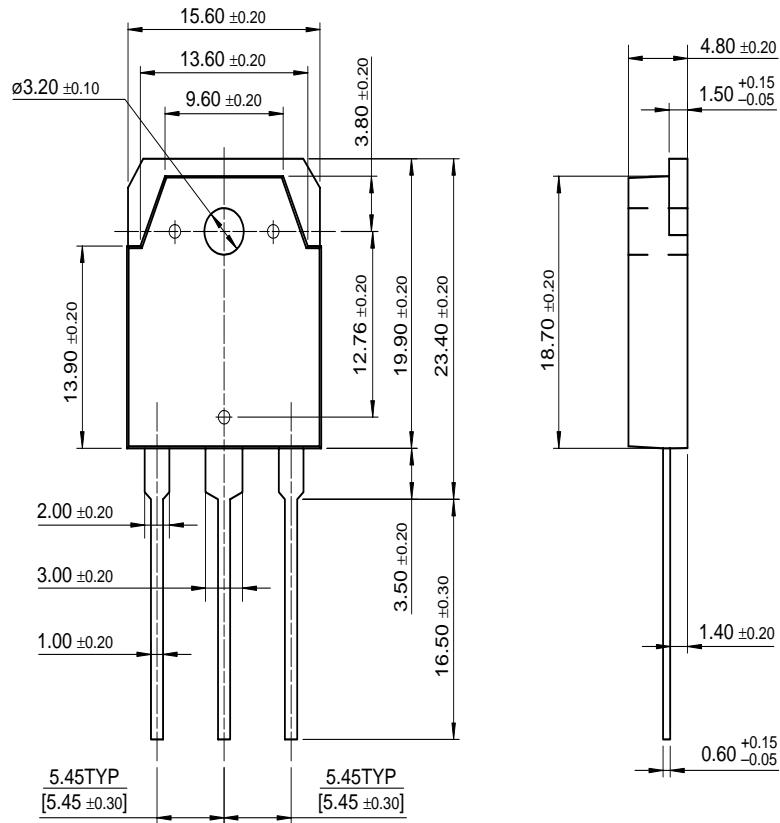


Figure 5. Turn Off Time

Package Demensions

TO-3P



Dimensions in Millimeters

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